[5mks]

## Paper/Subject Code: 58652/Engineering Physics-I F.E. (All Branches) (Rev-2019) 'C' 5 cheme) (CB) 5em-I

(2 Hours)

[Total Marks: 60]

N.B.: (1) Question No. 1 is compulsory.

- (2) Attempt any three questions from Q.2 to Q.6.
- (3) Assume suitable data wherever required.
- (4) Figures to the right indicate marks.
- [15mks] Q1. Attempt any five
- a. Draw the following planes in a cubic unit cell (121), (100), (011).
- b. The diameter of 5th dark ring in Newton's ring experiment was found to be 0,42 cm. Determine the diameter of 10th dark ring in the same set up.
- c. An electron is bound in a one-dimensional potential well of width 2 A° but of infinite height. Find its energy values in the ground state and in first excited state.
- d. Define superconductivity and explain the terms critical temperature and critical magnetic field.
- e. Find the resistivity of intrinsic germanium at 300 K. Given density of carriers is 2.5 x 10<sup>19</sup> /m³, mobility of electrons is 0.39 m<sup>2</sup>/volt-sec and mobility of holes is 0.19 m<sup>2</sup>/volt-sec.
- f. What are matter Waves? State three properties of matter waves.
- g. Explain the formation of colours in thin film.
- Q2 a) State Hall Effect. Obtain an expression for Hall voltage. Calculate the mobility of charge carriers in a doped Si, whose conductivity is 100 per ohm meter and Hall coefficient is  $3.6 \times 10^{-4} \,\mathrm{m}^3/\mathrm{C}$ .
- b) Obtain an expression for Optical Path Difference in a thin film of uniform thickness observed in reflected light. Hence obtain conditions for maxima and minima. [7mks]
- Q3a) Explain with neat diagram the effect of doping and temperature on the fermi level in N type extrinsic semiconductor. What is the probability of an electron being thermally excited to the conduction band in Si at 20° C. The band gap energy is 1.12 eV
- b) Show that the energy of an electron in a one-dimensional deep potential well of infinite height varies as the square of the natural numbers.
- Q4.a) Explain Bragg's spectrometer for the investigation of crystal structure with the help of a neat diagram. [5mks]
- b) Derive one dimensional Schrödinger's time dependent equation for matter waves.

## Paper / Subject Code: 58652 / Engineering Physics - I

c). White light is incident on a soap film at an angle sin (4/5) and the reflected light is observed with a spectroscope. It is found that two consecutive dark bands correspond to wavelength 6100 A° and 6000 A°. If the refractive index of the film is 4/3, calculate its thickness. [5mks]

Q5 a) Find the de Broglie wavelength of (i) an electron accelerated through a potential difference of 182 Volts and (ii) 1 Kg object moving with a speed of 1 m/s. Comparing the results, explain why is the wave nature of matter not apparent in daily observations? [5mks]

b). Derive an expression for interplanar spacing in a cubic unit cell?

[5mks]

c) Explain the principle and working of Supercapacitors?

[5mks]

Q6a) Explain principle, construction and working of Light Emitting Diode?

[5mks]

b). State Meissner's effect. Show that superconductors exhibit perfect diamagnetism

[5mks]

c). We wish to coat a flat slab of glass with refractive index 1.5 with a thinnest possible film of transparent material so that light of wavelength 600 nm incident normally is not reflected. We have two materials to choose from  $M_1$  ( $\mu$ = 1.21) and  $M_2$  ( $\mu$  =1.6). Which one would be appropriate? What will be the minimum thickness of coating?

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